## INTEGRATED CIRCUITS



Product data Supersedes data of 2000 Aug 30 File under Integrated Circuits — ICL03

2001 Dec 20





## **CBTD3384**

#### **FEATURES**

- 5  $\Omega$  switch connection between two ports
- TTL compatible control input and output levels
- Designed to be used in 5 V to 3.3 V level shifting applications
- Latch-up protection exceeds 500 mA per JESD78
- ESD protection exceeds 2000 V HBM per JESD22-A114, and 1000 V CDM per JESD22-C101

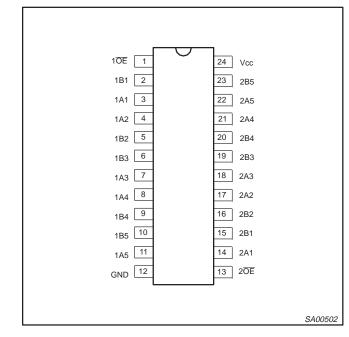
#### DESCRIPTION

The CBTD3384 provides ten bits of high-speed TTL-compatible level shifting bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The gate voltage of the enabled switch is lowered by a diode to allow convenient level shifting between 5 V and 3.3 V levels on either side of the CBTD3384.

The CBTD3384 device is organized as two 5-bit bus switches with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, the switch is on and port A is connected to B. When  $\overline{OE}$  is high, the switch is open and high-impedance state exists between the two ports.

The CBTD3384 is characterized for operation from -40 to +85 °C.

#### **PIN CONFIGURATION**



#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 13	1 <u>0E</u> , 2 <u>0E</u>	Output enables
3, 4, 7, 8, 11	1A1–1A5	Inputs
14, 17, 18, 21, 22	2A1–2A5	Inputs
2, 5, 6, 9, 10	1B1–1B5	Outputs
15, 16, 19, 20, 23	2B1–2B5	Outputs
12	GND	Ground (0V)
24	V <sub>CC</sub>	Positive supply voltage

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25 °C; GND = 0 V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	C <sub>L</sub> = 50 pF; V <sub>CC</sub> = 5 V	250	ps
C <sub>IN</sub>	Input capacitance	$V_I = 0 V \text{ or } V_{CC}$	3	pF
C <sub>OUT</sub>	Output capacitance	Outputs disabled; $V_O = 0 V \text{ or } V_{CC}$	6	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; $V_{CC}$ = 5.5 V	0.2	μΑ

#### **ORDERING INFORMATION**

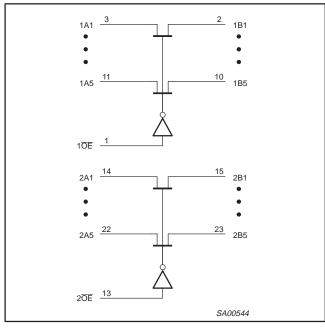
PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
24-Pin Plastic SO	−40 to +85 °C	CBTD3384D	SOT137-1
24-Pin Plastic SSOP	−40 to +85 °C	CBTD3384DB	SOT340-1
24-Pin Plastic SSOP (QSOP)	−40 to +85 °C	CBTD3384DK	SOT556-1
24-Pin Plastic TSSOP	−40 to +85 °C	CBTD3384PW	SOT355-1

Standard packing quantities and other packaging data is available at www.philipslogic.com/packaging.

#### Product data

## **CBTD3384**

#### LOGIC SYMBOL



#### **FUNCTION TABLE**

INPUTS		OUTPUTS		
10E	2 <mark>0E</mark>	1A, 1B	2A, 2B	
L	L	1A = 1B	2A= 2B	
L	Н	1A = 1B	Z	
н	L	Z	2A = 2B	
н	Н	Z	Z	

= High voltage level н

L = Low voltage level

Ζ = High impedance "off" state

#### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current		-50	mA
VI	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
I <sub>SW</sub>	DC output diode current	V <sub>O</sub> < 0	±128	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C. 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMPOL	SYMBOL PARAMETER		LIMITS		
STWBUL		Min	Max	UNIT	
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V	
V <sub>IH</sub>	High-level input voltage	2.0		V	
V <sub>IL</sub>	Low-level Input voltage	—	0.8	V	
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C	

## **CBTD3384**

SYMBOL	PARAMETER	TEST CONDITIONS	T <sub>amb</sub> =	= –40 °C to ⋅	+85 °C	UNIT
			Min	Typ <sup>1</sup>	Max	
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5 \text{ V}; \text{ I}_{I} = -18 \text{ mA}$	—	—	-1.2	V
V <sub>OH</sub>	Output high pass voltage	See Figure 1	—	—	—	V
Ц	Input leakage current	$V_{CC}$ = 5.5 V; $V_I$ = GND or 5.5 V	—	—	±1	μΑ
I <sub>CC</sub>	Quiescent supply current <sup>2</sup>	$V_{CC} = 5.5 \text{ V}; I_O = 0, V_I = V_{CC} \text{ or GND};$ 1 $\overline{OE}=2\overline{OE}=GND$	—	—	1.5	mA
ΔI <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 5.5 V, one input at 3.4 V, other inputs at $V_{CC}$ or GND	—	—	2.5	mA
CI	Control pins	$V_{I}=3 V \text{ or } 0$	—	3.2	—	pF
C <sub>I(OFF)</sub>	Port off capacitance	$V_{O} = 3 V \text{ or } 0, \overline{OE} = V_{CC}$	—	6	—	pF
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}; \text{ I}_{I} = 64 \text{ mA}$	—	5	7	
r <sub>on</sub> <sup>3</sup>	On-resistance	$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}; \text{ I}_{I} = 30 \text{ mA}$	—	5	7	Ω
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 2.4 \text{ V}; \text{ I}_{I} = -15 \text{ mA}$	—	17	50	

NOTES:

1. All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_{amb} = 25 \text{ °C}$ 2. This is the increase in supply current for each input that is at the specified TTL voltage level rather than  $V_{CC}$  or GND 3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

#### **AC CHARACTERISTICS**

GND = 0 V;  $t_R = t_F = 2.5 \text{ nS}$ ;  $C_L = 50 \text{ pF}$ 

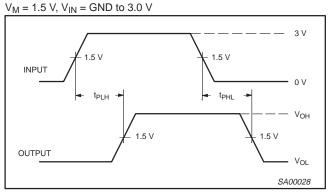
	SYMBOL PARAMETER DESCRIPTION		LIMITS		
SYMBOL			−40 °C to +85 °C V <sub>CC</sub> = 5 V ± 0.5 V		
		Min	Mean	Max	
t <sub>pd</sub>	Propagation delay <sup>1</sup>	—	—	250	ps
t <sub>PZH</sub>	Output enable time to High level	2.3	4.3	7.0	ns
t <sub>PHZ</sub>	Output disable time from High level	1.7	2.4	5.3	ns
t <sub>PZL</sub>	Output enable time to Low level	2.3	4.9	7.5	ns
t <sub>PLZ</sub>	Output disable time from Low level	1.7 4.2 5.3		ns	

NOTE:

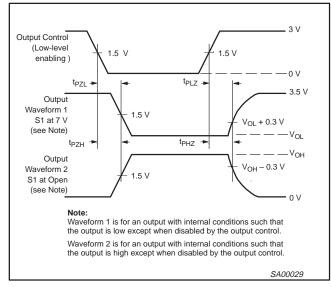
1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

## CBTD3384

#### AC WAVEFORMS

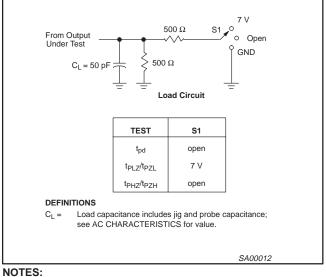


#### Waveform 1. Input (An) to Output (Yn) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

#### **TEST CIRCUIT AND WAVEFORMS**



- 1. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- 2. The outputs are measured one at a time with one transition per measurement.

## CBTD3384

#### **TYPICAL CHARACTERISTICS**

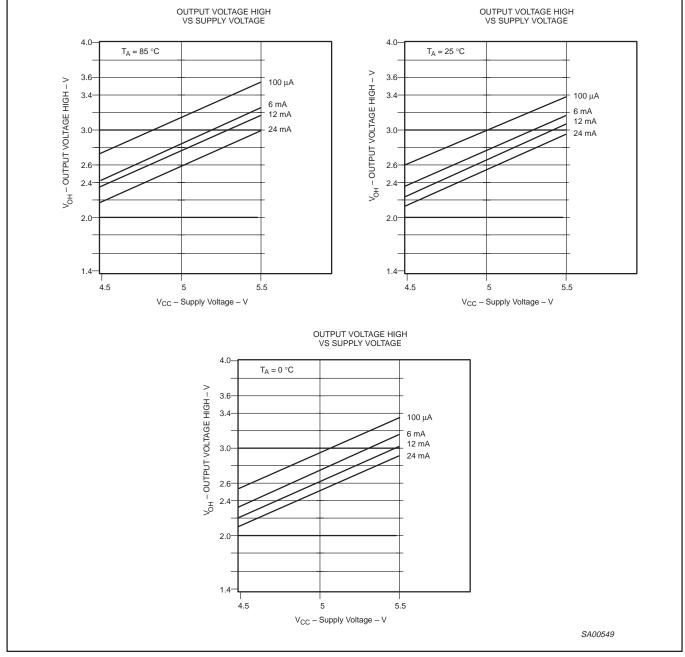
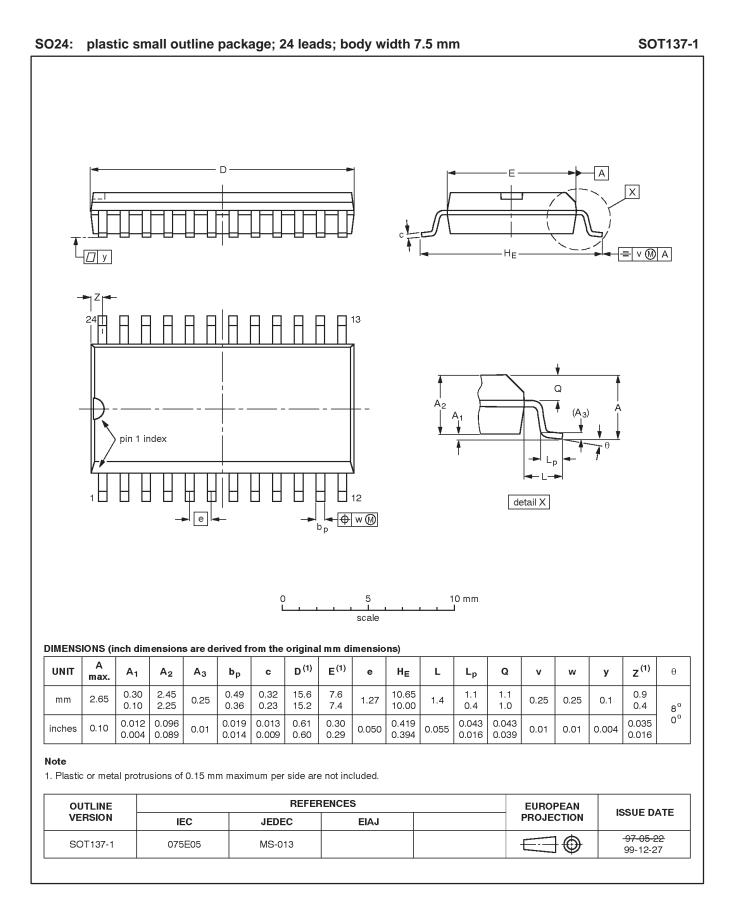
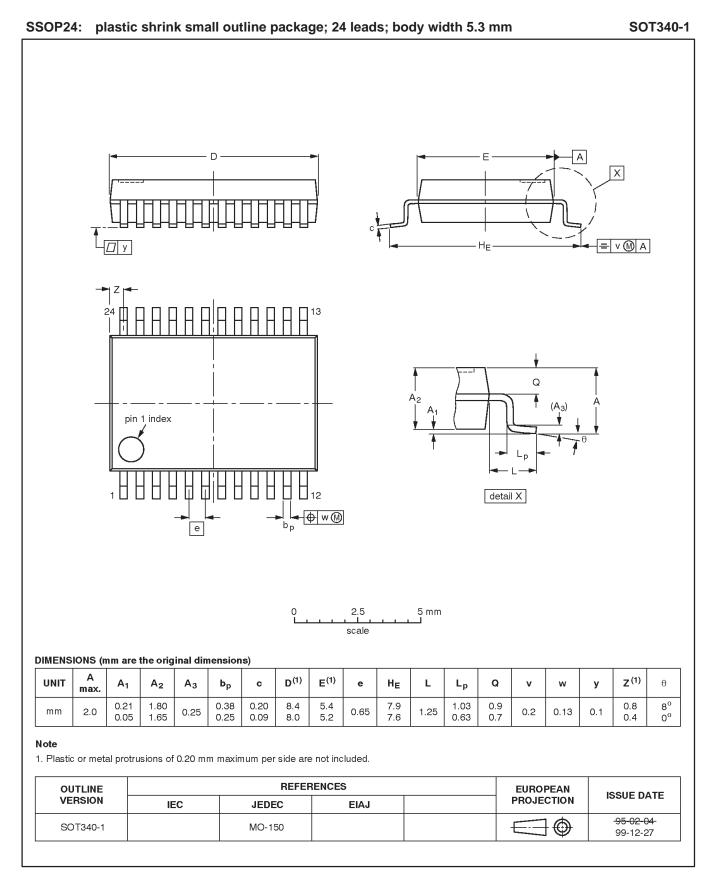


Figure 1.  $V_{OH}$  values ( $V_{in} = V_{CC}$ )

## CBTD3384



### CBTD3384



8

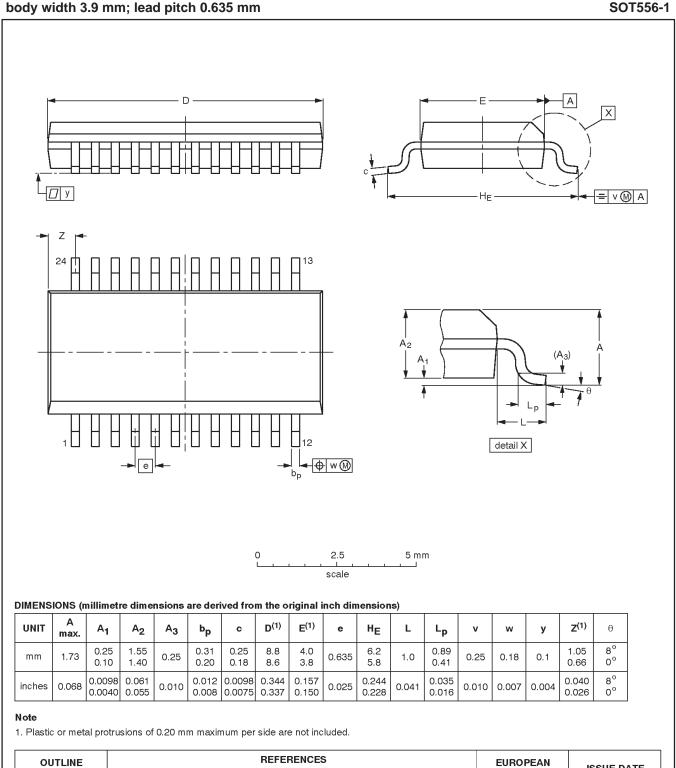
**CBTD3384** 

**ISSUE DATE** 

99-05-05

99-12-27

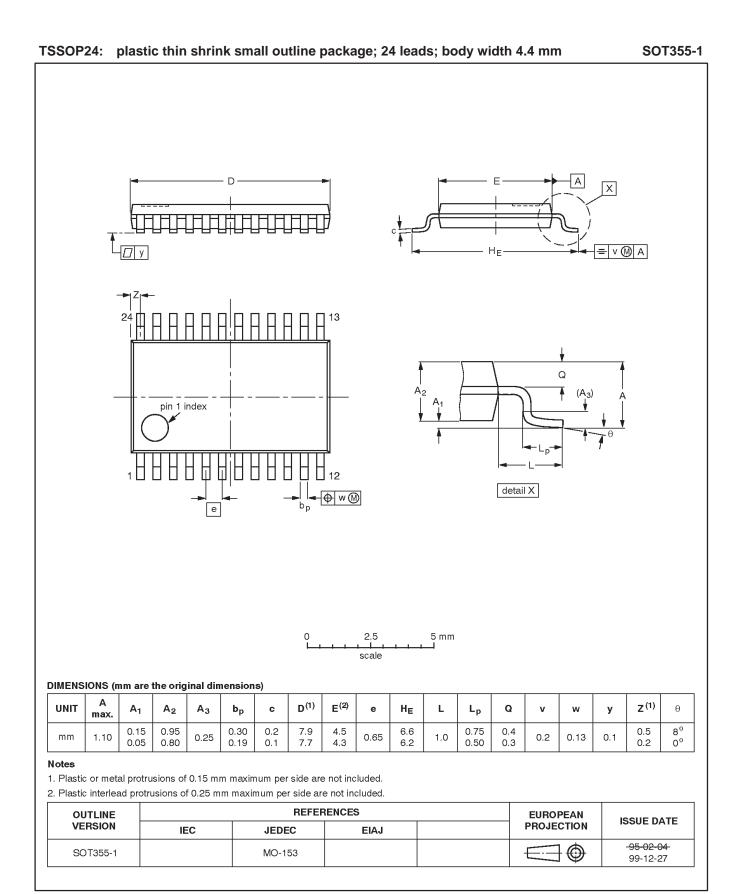
Product data



#### SSOP24: plastic shrink small outline package; 24 leads; body width 3.9 mm; lead pitch 0.635 mm

## Product data

CBTD3384



#### 2001 Dec 20 Downloaded from <u>Elcodis.com</u> electronic components distributor

10

CBTD3384

NOTES

## CBTD3384

#### Data sheet status

Data sheet status <sup>[1]</sup>	Product status <sup>[2]</sup>	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

#### Definitions

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

**Right to make changes** — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

#### Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +3

Fax: +31 40 27 24825

© Koninklijke Philips Electronics N.V. 2001 All rights reserved. Printed in U.S.A.

Date of release: 12-01

For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com

Document order number:

9397 750 09248

Let's make things better.





Semiconductors

Philips